NSN 5961-01-009-6315

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-009-6315 **Inclosure Material:** Metal **Overall Length:** 0.320 inches **Overall Diameter:** 0.437 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage, dc and 100.0 collector to emitter voltage, dc and 4.0 emitter to collector voltage, dc **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 11.6 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0